

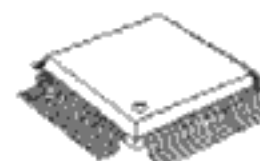
CMOS 8-Bit Microcontroller

TMP87PH48U/DF, TMP87PM48U/DF

The TMP87PH48 is a one-time PROM microcontroller with low-power 128 Kbits (16 Kbytes) electrically programmable read only memory for the TMP87CH48 system evaluation. The TMP87PM48 is a One-time PROM microcontroller with low-power 256 Kbits (32 Kbytes) electrically programmable read only memory for the TMP87CM48 system evaluation. The TMP87PH48/PM48 are pin compatible with the TMP87CH48/CM48. The operations possible with the TMP87CH48/CM48 can be performed by writing programs to PROM. The TMP87PH48/PM48 can write and verify in the same way as the TC57256AD using an adaptor sockets BM11117/BM11147 and an EPROM programmer.

Product No.	ROM	RAM	Package	Adapter Socket
TMP87PH48U TMP87PH48DF	16 K × 8 bits	512 × 8 bits	P-LQFP64-1010-0.50 P-QFP64-1414-0.80A	BM11117 BM11147
TMP87PM48U TMP87PM48DF	32 K × 8 bits	1 K × 8 bits	P-LQFP64-1010-0.50 P-QFP64-1414-0.80A	BM11117 BM11147

P-LQFP64-1010-0.50

TMP87PH48U
TMP87PM48U

P-QFP64-1414-0.80A

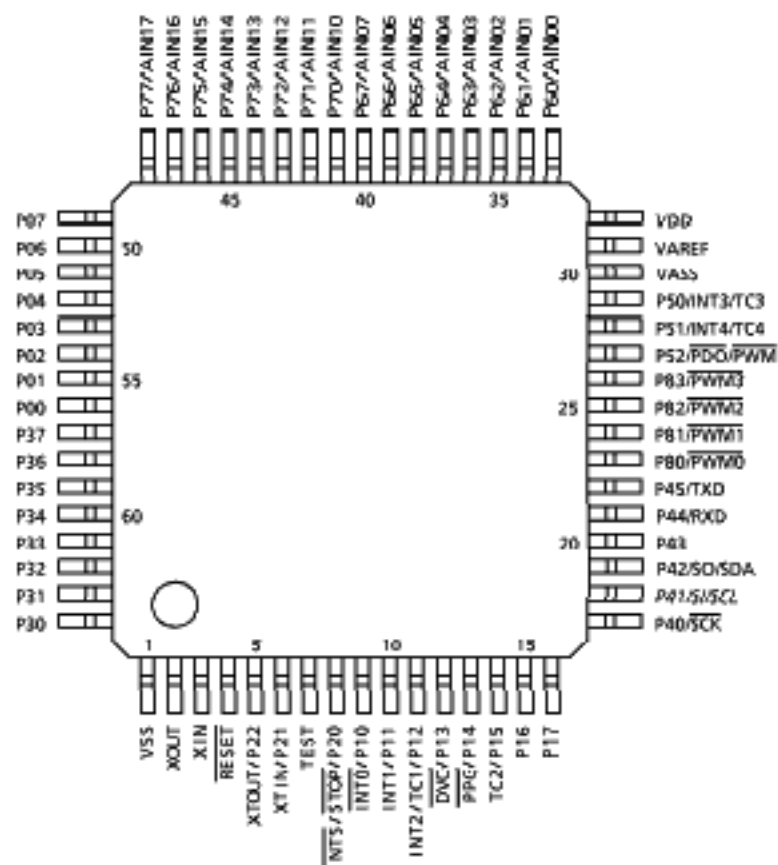
TMP87PH48DF
TMP87PM48DF

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Pin Assignments (Top View)

P-LQFP64-1010-0.50
P-QFP64-1414-0.80A



Pin Function

The TMP87PH48/PM48 have two modes: MCU and PROM.

(1) MCU mode

In this mode, the TMP87PH48/PM48 are pin compatible with the TMP87CH48/CM48 (Fix the TEST pin at low level).

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)
A14 to A8	Input	PROM address inputs	P76 to P70
A7 to A0			P81, P80, P45 to P40
D7 to D0	I/O	PROM data input/outputs	P07 to P00
$\overline{CE}$	Input	Chip enable signal input (active low)	P13
$\overline{OE}$		Output enable signal input (active low)	P14
VPP	Power supply	+ 12.5 V/5 V (Program supply voltage)	TEST
VCC		+ 5 V	VDD
GND		0 V	VSS
P37 to P34	I/O	Open	
P32 to P30			
P52 to P50			
P83, P82		Pull-up with resistance R1 for input processing	
P67 to P60			
P11, P12, P15	I/O	PROM mode setting pins. Be fixed at high level. (Pull-up with resistance R2)	
P21			
P77			
P17, P16, P10		PROM mode setting pins. Be fixed at low level.	
P133			
P22, P20			
RESET			
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal state.	
XOUT	Output		
VAREF	Power Supply	0 V (GND)	
VASS			

Operational Description

The following explains the TMP87PH48/PM48 hardware configuration and operation. The configuration and functions of the TMP87PH48/PM48 are the same as those of the TMP87CH48/CM48, except in that a one-time PROM is used instead of an on-chip mask ROM.

The TMP87PH48/PM48 are placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

1. Operating Mode

The TMP87PH48/PM48 have two modes: MCU and PROM.

1.1 MCU Mode

The MCU mode is activated by fixing the TEST/VPP pin at low level.

In the MCU mode, operation is the same as with the TMP87CH48/CM48 (The TEST/VPP pin cannot be used open because TMP87PH48/PM48 have no built-in pull-down resistance).

1.1.1 Program Memory

The TMP87PH48/PM48 have a 16K × 8-bit (Addresses C000_H to FFFF_H in the MCU mode, addresses 4000_H to 7FFF_H in the PROM mode) the TMP87PM48 has a 32K × 8 bit (Address 8000_H to FFFF_H in the MCU mode, addresses 0000_H to 7FFF_H in the PROM mode) of program memory (OTP).

To use the TMP87PH48/PM48 as the system evaluation for the TMP87CH48/CM48, the program should be written to the program memory area as shown in Figure 1-1.

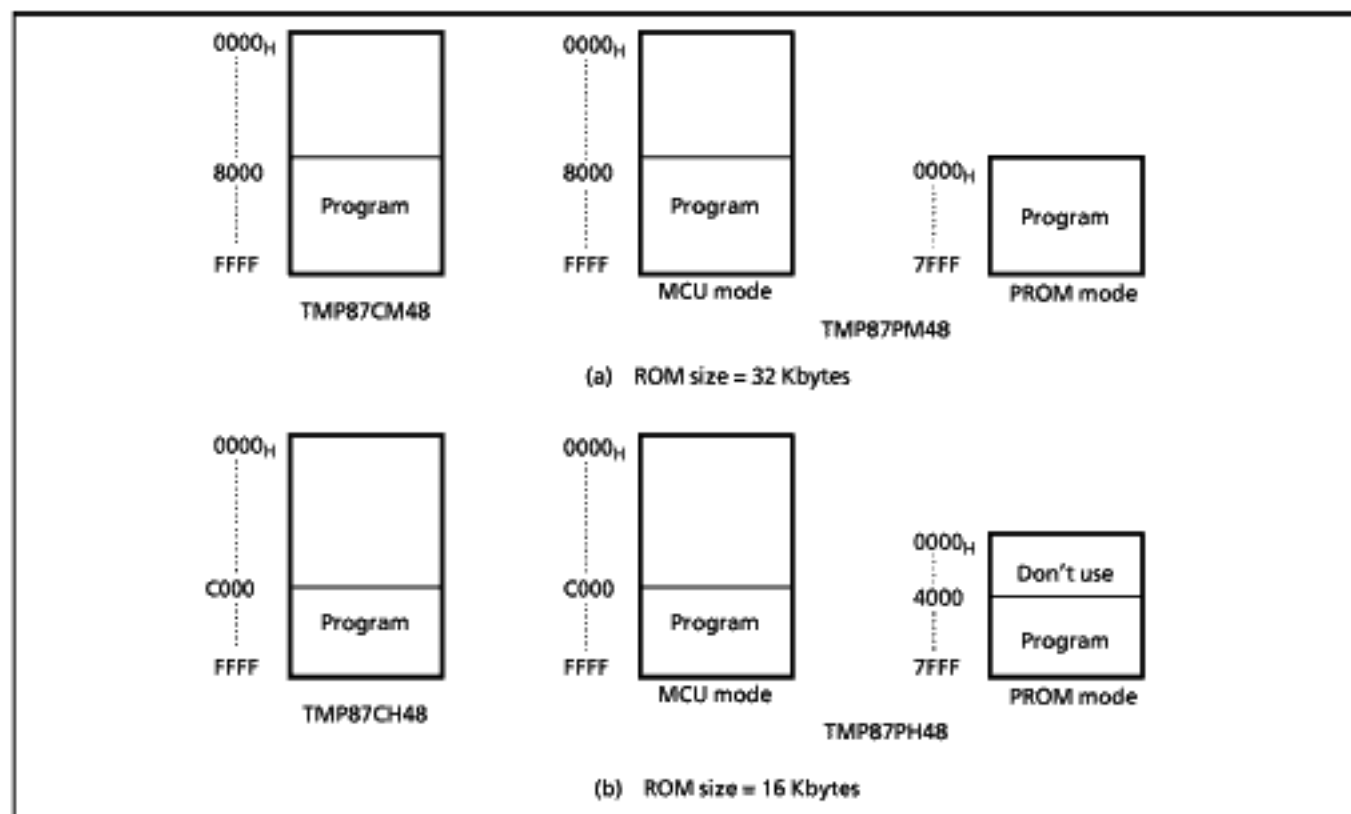


Figure 1-1. Program Memory Area

Note: Either write the data FF_H to the unused area or set the PROM programmer to access only the program storage area.

Electrical Characteristics

(1) TMP87PH48

Absolute Maximum Ratings

(V_{SS} = 0 V)

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{DD}		- 0.3 to 6.5	V
Input voltage	V _{IN}		- 0.3 to V _{DD} + 0.3	V
Output voltage	V _{OUT}		- 0.3 to V _{DD} + 0.3	V
Output current (Per 1 pin)	I _{OUT1}	Ports P0, P1, P2, P4, P5, P6, P7, P8	3.2	mA
	I _{OUT2}	Port P3	30	
Output current (Total)	Σ I _{OUT1}	Ports P0, P1, P2, P4, P5, P6, P7, P8	120	mA
	Σ I _{OUT2}	Port P3	120	
Power dissipation	PD		350	mW
Soldering temperature (Time)	T _{sld}		260 (10 s)	°C
Storage temperature	T _{stg}		- 55 to 125	°C
Operating temperature	T _{opr}		- 40 to 85	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

(V_{SS} = 0 V, T_{opr} = - 40 to 85°C)

Parameter	Symbol	Pins	Conditions		Min	Max	Unit
Supply voltage	V _{DD}		f _c = 8 MHz	NORMAL 1/2 modes	4.5	5.5	V
				IDLE 1/2 modes			
			f _c = 4.2 MHz	NORMAL 1/2 modes	2.7		
				IDLE 1/2 modes			
			f _s = 32.768 kHz	SLOW mode			
				SLEEP mode			
	STOP mode	2.0					
Input high voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V		V _{DD} × 0.70	V _{DD}	V
	V _{IH2}	Hysteresis input			V _{DD} × 0.75		
	V _{IH3}		V _{DD} < 4.5 V	V _{DD} × 0.90			
Input low voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V		0	V _{DD} × 0.30	V
	V _{IL2}	Hysteresis input				V _{DD} × 0.25	
	V _{IL3}		V _{DD} < 4.5 V	V _{DD} × 0.10			
Clock frequency	f _c	XIN, XOUT	V _{DD} = 4.5 to 5.5 V		0.4	8.0	MHz
			V _{DD} = 2.7 to 5.5 V			4.2	
	f _s	XTIN, XTOUT			30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (Supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: The condition of clock frequency is in NORMAL 1/2 modes and IDLE 1/2 modes.

DC Characteristics

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis voltage	V _{HS}	Hysteresis inputs	V _{DD} = 5.0 V	—	0.9	—	V
Input current	I _{IN1}	TEST	V _{DD} = 5.5 V V _{IN} = 5.5 V/0 V	—	—	± 2	μA
	I _{IN2}	Open drain ports, Tri-state ports					
	I _{IN3}	RESET, STOP					
Input resistance	R _{IN2}	RESET	V _{DD} = 5.0 V	100	220	450	kΩ
Output leakage current	I _{LO}	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	—	—	2	μA
		Tri-state ports	V _{DD} = 5.5 V, V _{OUT} = 5.5/0 V	—	—	± 2	
Output high voltage	V _{OH2}	Tri-state ports	V _{DD} = 4.5 V, I _{OH} = -0.7 mA	4.1	—	—	V
Output low voltage	V _{OL}	Except for XOUT and P3	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	—	—	0.4	mA
Output low current	I _{OL3}	P3	V _{DD} = 4.5 V, V _{OL} = 1.0 V	—	20	—	mA
Supply current in NORMAL 1, 2 modes	I _{DD}		V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V f _c = 8 MHz f _s = 32.768 kHz	—	4.5	5.5	mA
Supply current in IDLE 1, 2 modes				—	2.5	4.0	mA
Supply current in NORMAL 1, 2 modes			V _{DD} = 3.0 V, V _{IN} = 2.8 V/0.2 V V _{IN} = 4.19 MHz f _s = 32.768 kHz	—	1.75	3.0	mA
Supply current in IDLE 1, 2 modes				—	1.25	2.0	mA
Supply current in SLOW mode			V _{DD} = 3.0 V V _{IN} = 2.8 V/0.2 V f _s = 32.768 kHz	—	20	30	μA
Supply current in SLEEP mode				—	10	20	μA
Supply current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V	—	0.5	10	μA

Note 1: Typical values show those at T_{opr} = 25°CNote 2: Input Current I_{IN1}, I_{IN3}: The current through resistor is not included, when the input resistor (pull-up or pull-down) is contained.Note 3: I_{DD} except for I_{REF}.

AD Conversion Characteristics

(V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Conditions	Min	Typ.	Max			Unit
					ADCDR1	ADCDR2		
						ACK = 0	ACK = 1	
Analog reference voltage	V _{AREF}	V _{AREF} – V _{ASS} ≥ 2.5 V	2.7	–	V _{DD}			V
	V _{ASS}		V _{SS}	–	1.5			
Analog input voltage	V _{AIN}		V _{ASS}	–	V _{AREF}			V
Analog supply current	I _{REF}	V _{AREF} = 5.5 V, V _{ASS} = 0.0 V	–	0.5	1.2			mA
Nonlinearity error		V _{DD} = 5.0, V _{SS} = 0.0 V V _{AREF} = 5.000 V V _{ASS} = 0.000 V	–	–	± 1	± 3	± 2	LSB
Zero point error		or V _{DD} = 2.7, V _{SS} = 0.0 V V _{AREF} = 2.700 V V _{ASS} = 0.000 V	–	–	± 1	± 3	± 2	
Full scale error			–	–	± 1	± 3	± 2	
Total error			–	–	± 2	± 6	± 4	

Note 1: ΔV_{AREF} = V_{AREF} - V_{ASS}ADCDR1: 8 bits - AD conversion result (1LSB = ΔV_{AREF}/256)ADCDR2: 10 bits - AD conversion result (1LSB = ΔV_{AREF}/1024)

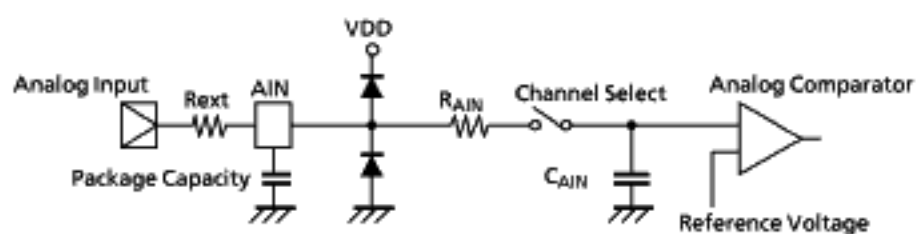
Note 2: Quantizing error is not contained in those errors.

AD Input Characteristics

(Topr = -40 to 85°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input impedance (Resistance)	R_{AIN}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	5	—	$\text{k}\Omega$
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	20	—	
Input impedance (Capacity)	C_{AIN}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	7	—	pF
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	7	—	
Source impedance	R_{ext}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	—	5	$\text{k}\Omega$
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	—	5	

Note: Input current (Output leak current) error (Max $\pm 2\text{ }\mu\text{A}$) and quantizing error (Max $\pm 4\text{LSB}$) for AD are contained.



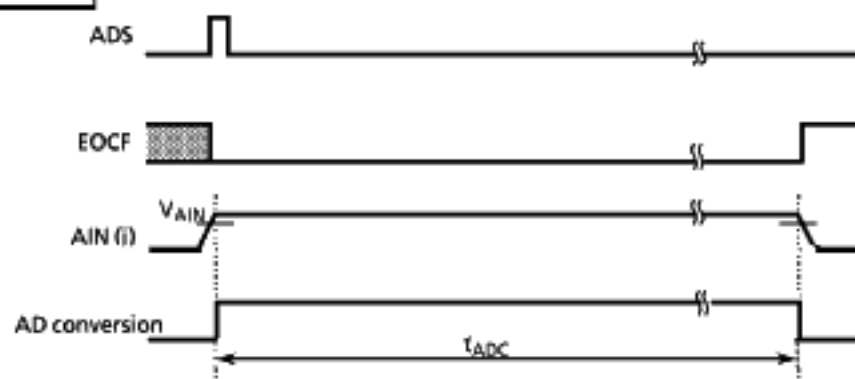
AD Pin Mode

AC Characteristics

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Conditions	V _{DD}	Min	Typ.	Max	Unit
Machine cycle time	t _{cy}	In NORMAL 1, 2 mode	4.5 to 5.5 V	0.5	–	10	μs
		In IDLE 1, 2 mode					
		In SLOW mode	2.7 to 5.5 V	117.6	–	133.3	
		In SLEEP mode					
High level clock pulse width	t _{WCH}	For external clock operation (XIN input), f _c = 8 MHz	4.5 to 5.5 V	62.5	–	–	ns
Low level clock pulse width	t _{WCL}						
High level clock pulse width	t _{WSH}	For external clock operation (XTIN input), f _s = 32.768 kHz	2.7 to 5.5 V	14.7	–	–	μs
Low level clock pulse width	t _{WSL}						
AD conversion time	t _{ADC}	ADCCR bit 4; ACK = 0	–	–	49 t _{cy}	–	ns
		ADCCR bit 4; ACK = 1	–	–	196 t _{cy}	–	

Timing of AD Conversion



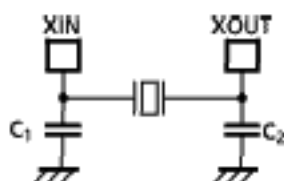
Note 1: During AD conversion, make the level of V_{AIN} stable.

Note 2: i = 17 to 10, 07 to 00

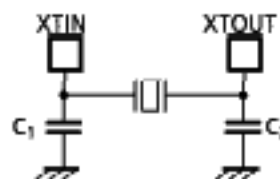
Recommended Oscillating Conditions

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Oscillator	Oscillation Frequency	VDD	Recommended Oscillator	Recommended Constant	
					C ₁	C ₂
High-frequency oscillation	Ceramic resonator	8 MHz	4.5 to 5.5 V	KYOCERA KBR8.0 M	30 pF	30 pF
		4 MHz	2.7 to 5.5 V	KYOCERA KBR4.0 MS		
				MURATA CSA4.00 MG		
	Crystal oscillator	8 MHz	4.5 to 5.5 V	TOYOCOM 2108 8.0000	20 pF	20 pF
		4 MHz	2.7 to 5.5 V	TOYOCOM 2048 4.0000		
Low-frequency oscillation	Crystal oscillator	32.768 kHz	2.7 to 5.5 V	NDK MX-38T	15 pF	15 pF



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note 1: When it is used in high electrical field, an electrical shield of the package is recommended to retain normal operations.

Note 2: TOYAMA MURATA MFG. CO., LTD (JAPAN)

The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change.

For up-to-date information, please refer to the following URL;

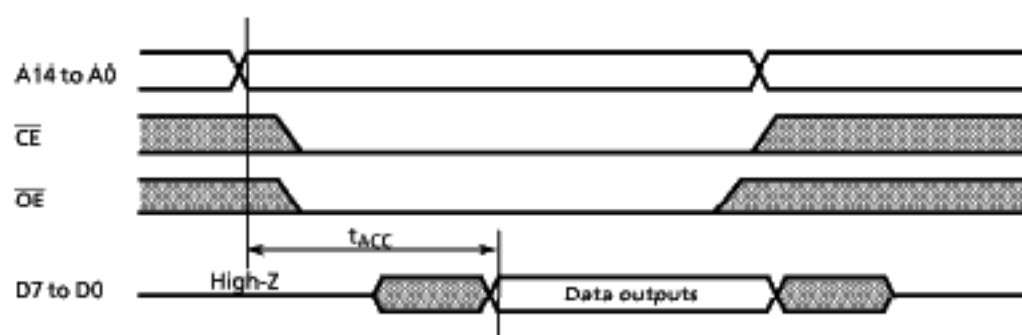
<http://www.murata.co.jp/search/index.html>

DC/AC Characteristics (PROM mode)

(V_{SS} = 0 V)

(1) Read operation

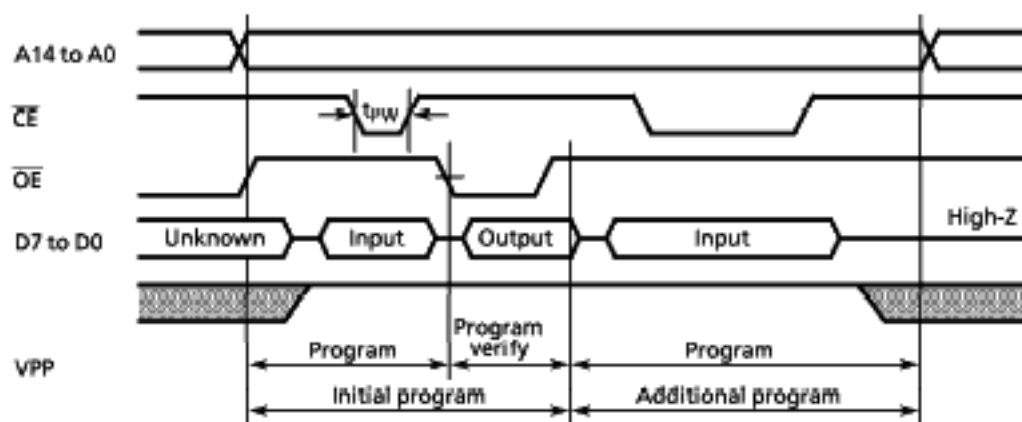
Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V _{IH4}		2.2	–	V _{CC}	V
Input low voltage	V _{IL4}		0	–	0.8	V
Power supply voltage	V _{CC}		4.75	–	6.5	V
Program power supply voltage	V _{PP}					
Address access time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	–	1.5 t _{cyc} + 300	–	ns

Note: t_{cyc} = 500 ns at 8 MHz

Timing Waveforms of Read Operation

(2) Program Operation (High-speed write mode - I) ($T_{opr} = 25 \pm 5^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V_{IH4}		2.2	–	V_{CC}	V
Input low voltage	V_{IL4}		0	–	0.8	V
Power supply voltage	V_{CC}		5.75	–	6.5	V
Program power supply voltage	V_{PP}		12.0	12.5	13.0	V
Initial program pulse width	t_{PW}	$V_{CC} = 6.0\text{ V} \pm 0.25\text{ V}$, $V_{PP} = 12.5\text{ V} \pm 0.5\text{ V}$	0.95	1.0	1.05	ms

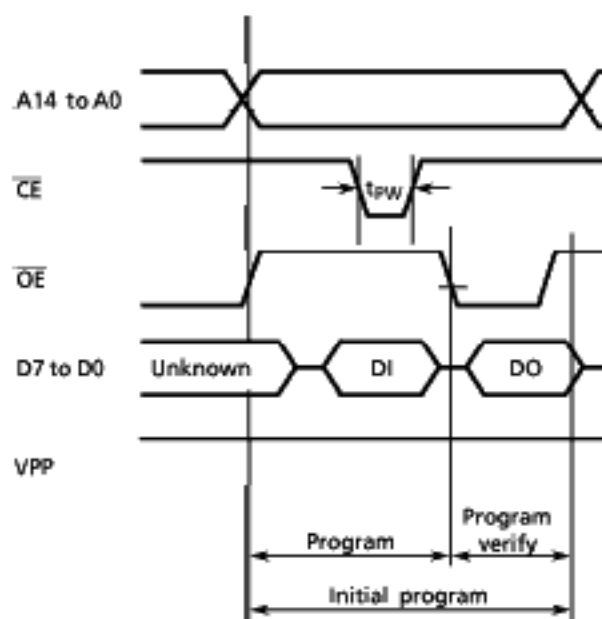


Timing Waveforms of Programming Operation

- Note 1:** When V_{CC} power supply is turned on or after, V_{PP} must be increased.
When V_{CC} power supply is turned off or before, V_{PP} must be decreased.
- Note 2:** The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.5\text{ V} \pm 0.5\text{ V}$) to the V_{PP} pin as the device is damaged.
- Note 3:** Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

(3) Program operation (High-speed write mode -II) ($T_{opr} = 25 \pm 5^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V_{IH4}		2.2	–	V_{CC}	V
Input low voltage	V_{IL4}		0	–	0.8	V
Supply voltage	V_{CC}		6.00	6.25	6.50	V
Program supply voltage	V_{PP}		12.50	12.75	13.0	V
Initial program pulse width	t_{PW}	$V_{CC} = 6.25\text{ V} \pm 0.25\text{ V}$, $V_{PP} = 12.75\text{ V} \pm 0.25\text{ V}$	0.095	0.1	0.105	ms



Note: DO: Data output (I0 to I7)
DI: Data input (I0 to I7)

Note 1: When V_{CC} power supply is turned on or after, V_{PP} must be increased.

When V_{CC} power supply is turned off or before, V_{PP} must be decreased.

Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.75\text{ V} \pm 0.25\text{ V}$) to the V_{PP} pin as the device is damaged.

Note 3: Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

Electrical Characteristics

(2) TMP87PM48

Absolute Maximum Ratings

(V_{SS} = 0 V)

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{DD}		- 0.3 to 6.5	V
Input voltage	V _{IN}		- 0.3 to V _{DD} + 0.3	V
Output voltage	V _{OUT}		- 0.3 to V _{DD} + 0.3	V
Output current (Per 1 pin)	I _{OUT1}	Ports P0, P1, P2, P4, P5, P6, P7, P8	3.2	mA
	I _{OUT2}	Port P3	30	
Output current (Total)	Σ I _{OUT1}	Ports P0, P1, P2, P4, P5, P6, P7, P8	120	mA
	Σ I _{OUT2}	Port P3	120	
Power dissipation	PD		350	mW
Soldering temperature (Time)	T _{sld}		260 (10 s)	°C
Storage temperature	T _{stg}		- 55 to 125	°C
Operating temperature	T _{opr}		- 40 to 85	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

(V_{SS} = 0 V, T_{opr} = - 40 to 85°C)

Parameter	Symbol	Pins	Conditions		Min	Max	Unit
Supply voltage	V _{DD}		f _c = 8 MHz	NORMAL 1/2 modes	4.5	5.5	V
				IDLE 1/2 modes			
			f _c = 4.2 MHz	NORMAL 1/2 modes	2.7		
				IDLE 1/2 modes			
			f _s = 32.768 kHz	SLOW mode	2.0		
				SLEEP mode			
	STOP mode						
Input high voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V		V _{DD} × 0.70	V _{DD}	V
	V _{IH2}	Hysteresis input			V _{DD} × 0.75		
	V _{IH3}		V _{DD} < 4.5 V	V _{DD} × 0.90			
Input low voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V		0	V _{DD} × 0.30	V
	V _{IL2}	Hysteresis input				V _{DD} × 0.25	
	V _{IL3}		V _{DD} < 4.5 V	V _{DD} × 0.10			
Clock frequency	f _c	XIN, XOUT	V _{DD} = 4.5 to 5.5 V		0.4	8.0	MHz
			V _{DD} = 2.7 to 5.5 V			4.2	
	f _s	XTIN, XTOUT			30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (Supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: The condition of clock frequency is in NORMAL 1/2 modes and IDLE 1/2 modes.

DC Characteristics

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis voltage	V _{H5}	Hysteresis inputs	V _{DD} = 5.0 V	—	0.9	—	V
Input current	I _{IN1}	TEST	V _{DD} = 5.5 V V _{IN} = 5.5 V/0 V	—	—	± 2	μA
	I _{IN2}	Open drain ports, Tri-state ports					
	I _{IN3}	RESET, STOP					
Input resistance	R _{IN2}	RESET	V _{DD} = 5.0 V	100	220	450	kΩ
Output leakage current	I _{LO}	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	—	—	2	μA
		Tri-state ports	V _{DD} = 5.5 V, V _{OUT} = 5.5/0 V	—	—	± 2	
Output high voltage	V _{OH2}	Tri-state ports	V _{DD} = 4.5 V, I _{OH} = -0.7 mA	4.1	—	—	V
Output low voltage	V _{OL}	Except for XOUT and P3	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	—	—	0.4	mA
Output low current	I _{OL3}	P3	V _{DD} = 4.5 V, V _{OL} = 1.0 V	—	20	—	mA
Supply current in NORMAL 1, 2 modes	I _{DD}		V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V f _c = 8 MHz f _s = 32.768 kHz	—	4.75	6.4	mA
Supply current in IDLE 1, 2 modes			V _{DD} = 3.0 V, V _{IN} = 2.8 V/0.2 V V _{IN} = 4.19 MHz f _s = 32.768 kHz	—	3.25	4.65	mA
Supply current in NORMAL 1, 2 modes				—	1.87	3.2	mA
Supply current in IDLE 1, 2 modes			V _{DD} = 3.0 V V _{IN} = 2.8 V/0.2 V f _s = 32.768 kHz	—	1.35	2.2	mA
Supply current in SLOW mode				—	20	30	μA
Supply current in SLEEP mode			V _{DD} = 3.0 V V _{IN} = 2.8 V/0.2 V f _s = 32.768 kHz	—	10	20	μA
Supply current in STOP mode				—	0.5	10	μA

Note 1: Typical values show those at T_{opr} = 25°CNote 2: Input Current I_{IN1}, I_{IN3}: The current through resistor is not included, when the input resistor (pull-up or pull-down) is contained.Note 3: I_{DD} except for I_{REF}.

AD Conversion Characteristics

(V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Conditions	Min	Typ.	Max			Unit
					ADCDR1	ADCDR2		
						ACK = 0	ACK = 1	
Analog reference voltage	V _{AREF}	V _{AREF} - V _{ASS} ≥ 2.5 V	2.7	—	V _{DD}			V
	V _{ASS}		V _{SS}	—	1.5			
Analog input voltage	V _{AIN}		V _{ASS}	—	V _{AREF}			V
Analog supply current	I _{REF}	V _{AREF} = 5.5 V, V _{ASS} = 0.0 V	—	0.5	1.2			mA
Nonlinearity error		V _{DD} = 5.0, V _{SS} = 0.0 V V _{AREF} = 5.000 V V _{ASS} = 0.000 V	—	—	± 1	± 3	± 2	LSB
Zero point error		or V _{DD} = 2.7, V _{SS} = 0.0 V V _{AREF} = 2.700 V V _{ASS} = 0.000 V	—	—	± 1	± 3	± 2	
Full scale error			—	—	± 1	± 3	± 2	
Total error			—	—	± 2	± 6	± 4	

Note 1: ΔV_{AREF} = V_{AREF} - V_{ASS}ADCDR1: 8 bits - AD conversion result (1LSB = ΔV_{AREF}/256)ADCDR2: 10 bits - AD conversion result (1LSB = ΔV_{AREF}/1024)

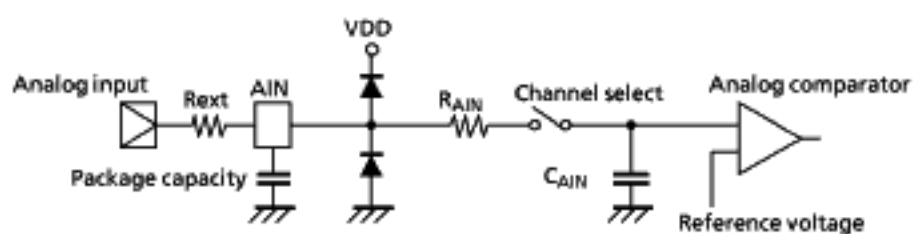
Note 2: Quantizing error is not contained in those errors.

AD Input Characteristics

(Topr = -40 to 85°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input impedance (Resistance)	R_{AIN}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	5	—	$\text{k}\Omega$
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	20	—	
Input impedance (Capacity)	C_{AIN}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	7	—	pF
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	7	—	
Source impedance	R_{ext}	$V_{DD} = 5.0\text{ V}$, Conversion time $23\text{ }\mu\text{s}$ ($f_c = 8\text{ MHz}$)	—	—	5	$\text{k}\Omega$
		$V_{DD} = 2.7\text{ V}$, Conversion time $43.8\text{ }\mu\text{s}$ ($f_c = 4.2\text{ MHz}$)	—	—	5	

Note: Input current (Output leak current) error (Max $\pm 2\text{ }\mu\text{A}$) and quantizing error (Max $\pm 4\text{LSB}$) for AD are contained.



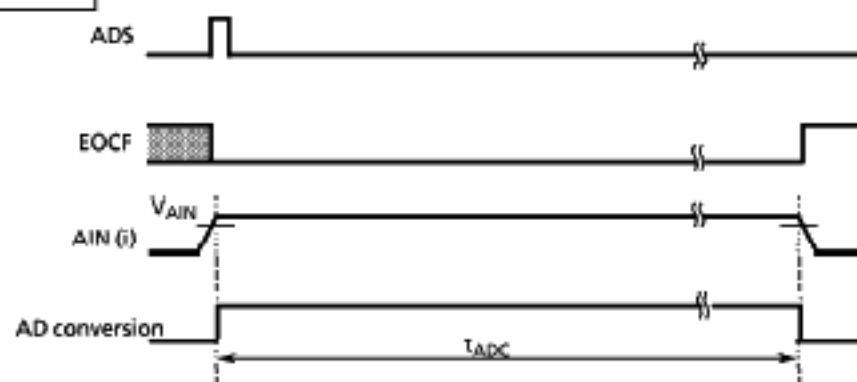
AD Pin Mode

AC Characteristics

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Symbol	Conditions	V _{DD}	Min	Typ.	Max	Unit
Machine cycle time	t _{cy}	In NORMAL 1, 2 mode	4.5 to 5.5 V	0.5	—	10	μs
		In IDLE 1, 2 mode	4.5 to 5.5 V	0.5	—	10	
		In SLOW mode	2.7 to 5.5 V	117.6	—	133.3	
		In SLEEP mode	2.7 to 5.5 V	117.6	—	133.3	
High level clock pulse width	t _{WCH}	For external clock operation (XIN input), f _c = 8 MHz	4.5 to 5.5 V	62.5	—	—	ns
Low level clock pulse width	t _{WCL}						
High level clock pulse width	t _{WSH}	For external clock operation (XTIN input), f _s = 32.768 kHz	2.7 to 5.5 V	14.7	—	—	μs
Low level clock pulse width	t _{WSL}						
AD conversion time	t _{ADC}	ADCCR bit 4 ; ACK = 0	—	—	49 t _{cy}	—	ns
		ADCCR bit 4 ; ACK = 1	—	—	196 t _{cy}	—	

Timing of AD Conversion



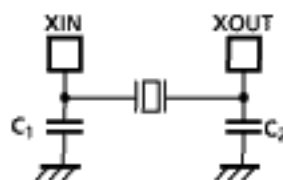
Note 1: During AD conversion, make the level of V_{AIN} stable.

Note 2: i = 17 to 10, 07 to 00

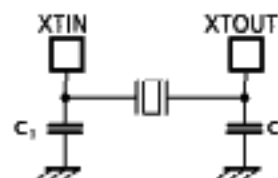
Recommended Oscillating Conditions

(V_{SS} = 0 V, T_{opr} = -40 to 85°C)

Parameter	Oscillator	Oscillation Frequency	VDD	Recommended Oscillator	Recommended Constant	
					C ₁	C ₂
High-frequency oscillation	Ceramic resonator	8 MHz	4.5 to 5.5 V	KYOCERA KBR8.0 M	30 pF	30 pF
		4 MHz	2.7 to 5.5 V	KYOCERA KBR4.0 M5		
				MURATA CSA4.00 MG		
	Crystal oscillator	8 MHz	4.5 to 5.5 V	TOYOCOM 210B 8.0000	20 pF	20 pF
		4 MHz	2.7 to 5.5 V	TOYOCOM 204B 4.0000		
Low-frequency oscillation	Crystal oscillator	32.768 kHz	2.7 to 5.5 V	NDK MX-38T	15 pF	15 pF



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note 1: When it is used in high electrical field, an electrical shield of the package is recommended to retain normal operations.

Note 2: TOYAMA MURATA MFG. CO., LTD (JAPAN)

The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change.

For up-to-date information, please refer to the following URL;

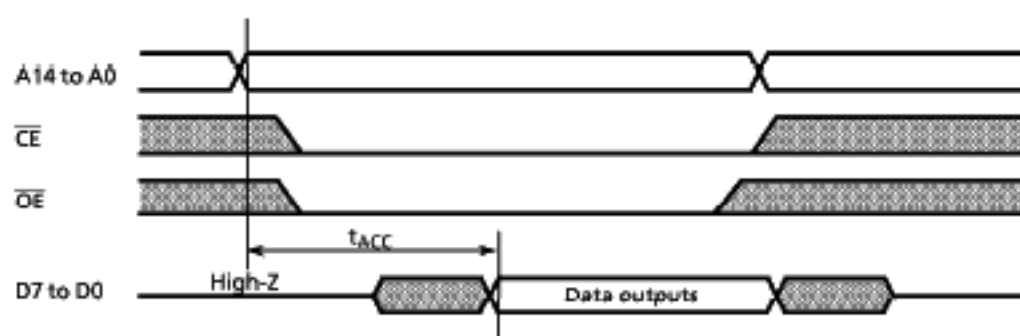
<http://www.murata.co.jp/search/index.html>

DC/AC Characteristics (PROM mode)

(V_{SS} = 0 V)

(1) Read operation

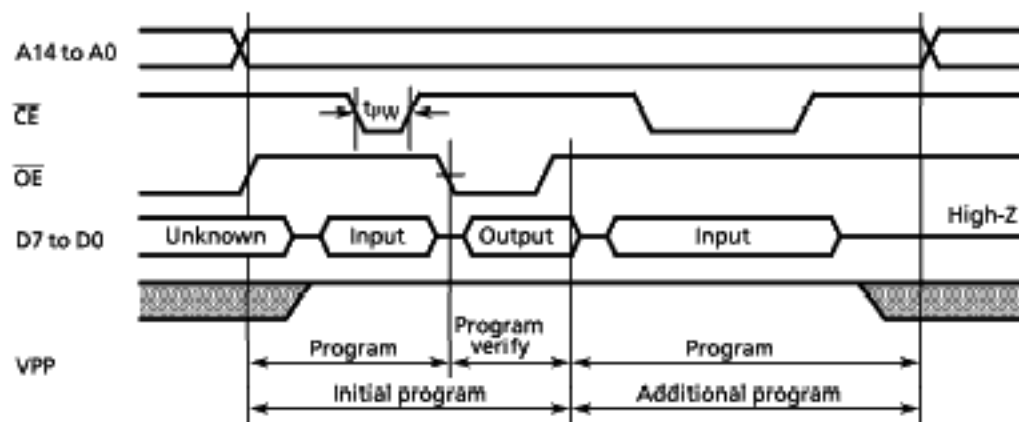
Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V _{IH4}		2.2	—	V _{CC}	V
Input low voltage	V _{IL4}		0	—	0.8	V
Power supply voltage	V _{CC}		4.75	—	6.5	V
Program power supply voltage	V _{PP}					
Address access time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	—	1.5 t _{cyc} + 300	—	ns

Note: t_{cyc} = 500 ns at 8 MHz

Timing Waveforms of Read Operation

(2) Program Operation (High-speed write mode - I) ($T_{opr} = 25 \pm 5^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V_{IH4}		2.2	–	V_{CC}	V
Input low voltage	V_{IL4}		0	–	0.8	V
Power supply voltage	V_{CC}		5.75	6.0	6.25	V
Program power supply voltage	V_{PP}		12.0	12.5	13.0	V
Initial program pulse width	t_{PW}	$V_{CC} = 6.0\text{ V} \pm 0.25\text{ V}$, $V_{PP} = 12.5 \pm 0.5\text{ V}$	0.95	1.0	1.05	ms

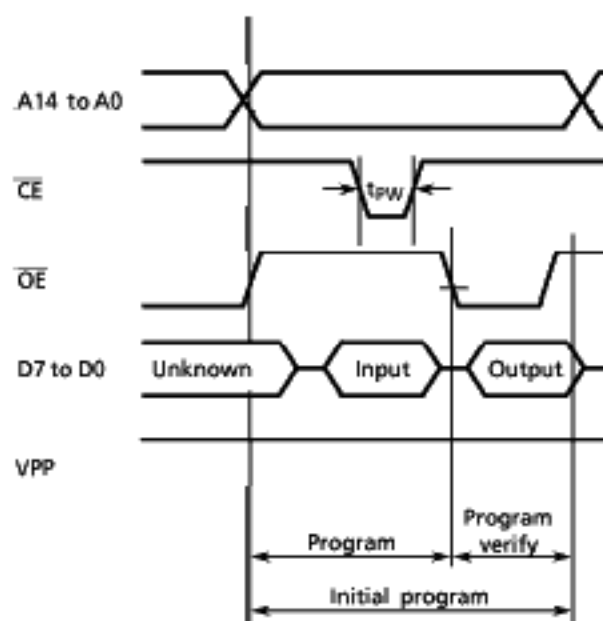


Timing Waveforms of Programming Operation

- Note 1:** When V_{CC} power supply is turned on or after, V_{PP} must be increased.
When V_{CC} power supply is turned off or before, V_{PP} must be decreased.
- Note 2:** The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.5\text{ V} \pm 0.5\text{ V}$) to the V_{PP} pin as the device is damaged.
- Note 3:** Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

(3) Program operation (High-speed write mode -II) ($T_{opr} = 25 \pm 5^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input high voltage	V_{IH4}		2.2	–	V_{CC}	V
Input low voltage	V_{IL4}		0	–	0.8	V
Supply voltage	V_{CC}		6.00	6.25	6.50	V
Program supply voltage	V_{PP}		12.50	12.75	13.0	V
Initial program pulse width	t_{PW}	$V_{CC} = 6.25\text{ V} \pm 0.25\text{ V}$, $V_{PP} = 12.75\text{ V} \pm 0.25\text{ V}$	0.095	0.1	0.105	ms



Note 1: When V_{CC} power supply is turned on or after, V_{PP} must be increased.

When V_{CC} power supply is turned off or before, V_{PP} must be decreased.

Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.75\text{ V} \pm 0.25\text{ V}$) to the V_{PP} pin as the device is damaged.

Note 3: Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.